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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Application Number	Unknown 10/509898
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				First Named Inventor	Hiroto OHTAKE
				Art Unit	Unknown 2818
				Examiner Name	Unknown HOANG-QUAN HO
Sheet	1	of	1	Attorney Docket Number	Q83944

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code ² (if known)		
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Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation ⁶
		Country Code ³	Number ⁴	Kind Code ⁵ (if known)			
HQA		JP	2000-36484	A	02-02-2000		No
		JP	2001-35832	A	02-09-2001		No
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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁶
HQA		H. Hanahata et al., "Dependency of Basic Properties of Porous Silica ILD Thin Films in the k Range 1.6-2.7 on CMP Compatibility", Conference Proceedings ULSI XVI, 2001, Materials Research Society, page 629.	

Examiner Signature		Date Considered	4/3/2006
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